ON Semiconductor

Is Now

To learn more about onsemi™, please visit our website at
www.onsemi.com

MC74AC646, MC74ACT646

Octal Transceiver/Register with 3-State Outputs (Non-inverting)

The MC74AC646/74ACT646 consist of registered bus transceiver circuits, with outputs, D−type flip−flops and control circuitry providing multiplexed transmission of data directly from the input bus or from the internal storage registers. Data on the A or B bus will be loaded into the respective registers on the LOW−to−HIGH transition of the appropriate clock pin (CAB or CBA). The four fundamental data handling functions available are illustrated Figures 1 to 4.

Features

- Independent Registers for A and B Buses
- Multiplexed Real−Time and Stored Data Transfers
- Choice of True and Inverting Data Paths
- 3−State Outputs
- 300 mil Slim Dual In−Line Package
- Outputs Source/Sink 24 mA
- ′ACT646 Has TTL Compatible Inputs
- These are Pb−Free Devices

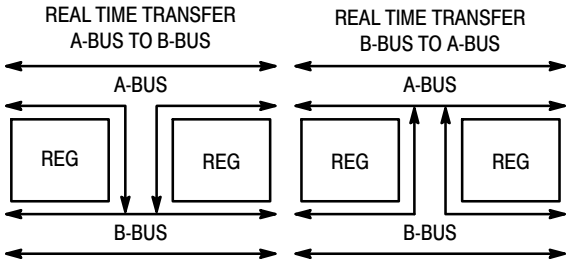


Figure 1.

Figure 2.

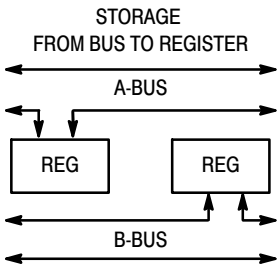


Figure 3.

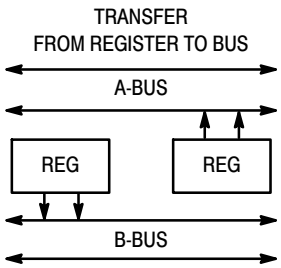
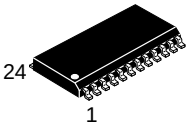


Figure 4.

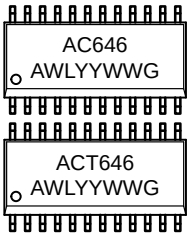
ON Semiconductor™

www.onsemi.com

MARKING DIAGRAMS



SO−24
DW SUFFIX
CASE 751E



A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

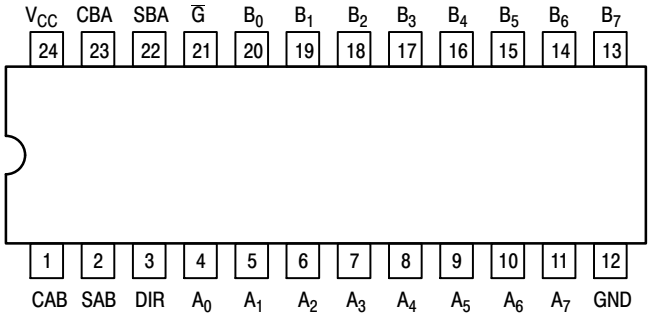


Figure 5. Pinout: 24−Lead Packages Conductors
(Top View)

PIN ASSIGNMENT

PIN	FUNCTION
A_0–A_7	Data Register Inputs Data Register A Outputs
B_0–B_7	Data Register B Inputs Data Register B Outputs
CAB, CBA	Clock Pulse Inputs
SAB, SBA	Transmit/Receive Inputs
DIR, $\overline{G}$	Output Enable Inputs

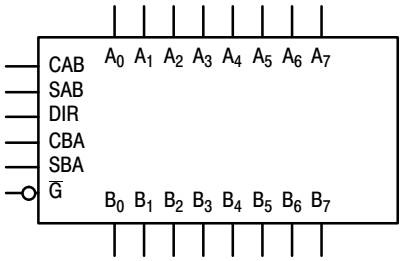
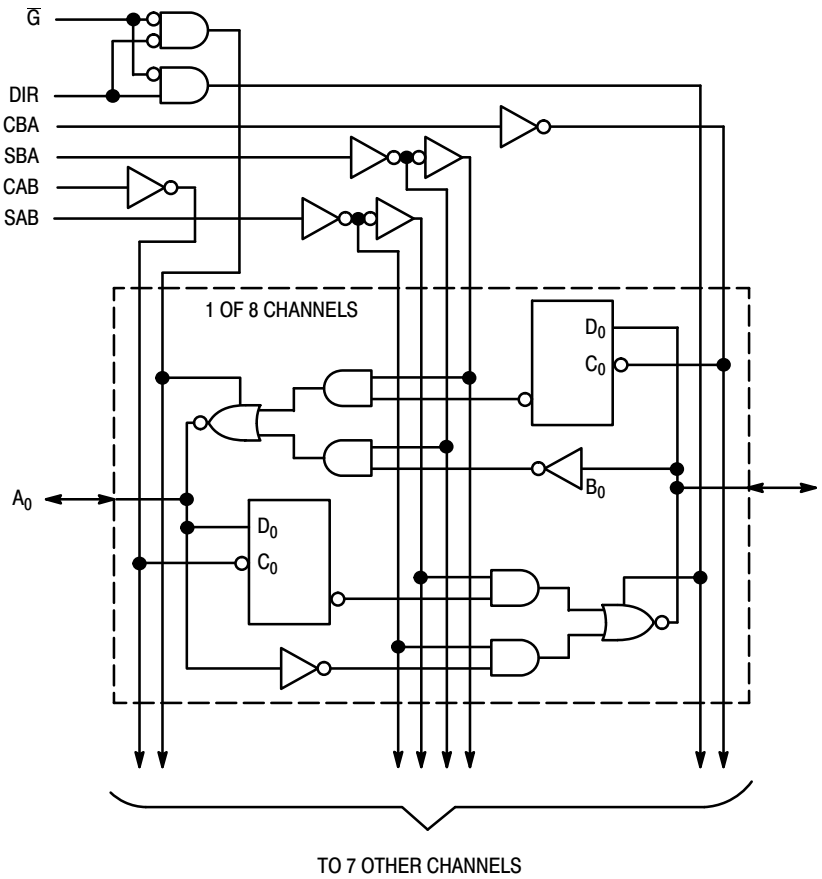


Figure 6. Logic Symbol



NOTE: This diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 7. Logic Diagram

FUNCTION TABLE

Inputs						Data I/O*		Operation or Function
$\overline{G}$	DIR	CAB	CBA	SAB	SBA	A_0–A_7	B_0–B_7	
H H	X X	H or L ⌐¬	H or L ⌐¬	X X	X X	Input	Input	Isolation Store A and B Data
L L	L L	X X	X X	X X	L H	Output	Input	Real Time B Data to A Bus Stored B Data to A Bus
L L	H H	X H or L	X X	L H	X X	Input	Output	Real Time A Data to B Bus Stored A Data to B Bus

*The data output functions may be enabled or disabled by various signals at the $\overline{G}$ and DIR inputs. Data input functions are always enabled; i.e., data at the bus pins will be stored on every LOW−to−HIGH transition of the appropriate clock inputs.

NOTE: H = HIGH Voltage Level; L = LOW Voltage Level; X = Immaterial; ⌐¬ = LOW−to−HIGH Transition

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)		−0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)		−0.5 to V_{CC} +0.5	V
V_{OUT}	DC Output Voltage (Referenced to GND) (Note 1)		−0.5 to V_{CC} +0.5	V
I_{IK}	DC Input Diode Current		±20	mA
I_{OK}	DC Output Diode Current		±50	mA
I_{OUT}	DC Output Sink/Source Current		±50	mA
I_{CC}	DC Supply Current, per Output Pin		±50	mA
I_{GND}	DC Ground Current, per Output Pin		±100	mA
T_{STG}	Storage Temperature Range		− 65 to + 150	°C
T_L	Lead temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		140	°C
θ_{JA}	Thermal Resistance (Note 2)		59.8	°C/W
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating	Oxygen Index: 30% − 35%	UL 94 V−0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	> 2000 > 200 > 1000	V
$I_{Latchup}$	Latchup Performance	Above V_{CC} and Below GND at 85°C (Note 6)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_{OUT} absolute maximum rating must be observed.
2. The package thermal impedance is calculated in accordance with JESD 51−7.
3. Tested to EIA/JESD22−A114−A.
4. Tested to EIA/JESD22−A115−A.
5. Tested to JESD22−C101−A.
6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	′AC	2.0	5.0	6.0	V
		′ACT	4.5	5.0	5.5	
V_{in}, V_{out}	DC Input Voltage, Output Voltage (Ref. to GND)		0	−	V_{CC}	V
t_r, t_f	Input Rise and Fall Time (Note 1) ′AC Devices except Schmitt Inputs	V_{CC} @ 3.0 V	−	150	−	ns/V
		V_{CC} @ 4.5 V	−	40	−	
		V_{CC} @ 5.5 V	−	25	−	
t_r, t_f	Input Rise and Fall Time (Note 2) ′ACT Devices except Schmitt Inputs	V_{CC} @ 4.5 V	−	10	−	ns/V
		V_{CC} @ 5.5 V	−	8.0	−	
T_A	Operating Ambient Temperature Range		−40	25	85	°C
I_{OH}	Output Current − High		−	−	−24	mA
I_{OL}	Output Current − Low		−	−	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. V_{in} from 30% to 70% V_{CC}; see individual Data Sheets for devices that differ from the typical input rise and fall times.
2. V_{in} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

Symbol	Parameter	V_{CC} (V)	74AC		74AC	Unit	Conditions
			T_A = +25°C		T_A = −40°C to +85°C		
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V	V_{OUT} = 0.1 V or V_{CC} − 0.1 V
V_{IL}	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	V_{OUT} = 0.1 V or V_{CC} − 0.1 V
V_{OH}	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I_{OUT} = −50 μA
		3.0 4.5 5.5	− − −	2.56 3.86 4.86	2.46 3.76 4.76	V	*V_{IN} = V_{IL} or V_{IH} −12 mA I_{OH} −24 mA −24 mA
V_{OL}	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	I_{OUT} = 50 μA
		3.0 4.5 5.5	− − −	0.36 0.36 0.36	0.44 0.44 0.44	V	*V_{IN} = V_{IL} or V_{IH} 12 mA I_{OL} 24 mA 24 mA
I_{IN}	Maximum Input Leakage Current	5.5	−	±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OZT}	Maximum 3-State Current	5.5	−	±0.6	±6.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	†Minimum Dynamic Output Current	5.5	−	−	75	mA	V_{OLD} = 1.65 V Max
I_{OHD}		5.5	−	−	−75	mA	V_{OHD} = 3.85 V Min
I_{CC}	Maximum Quiescent Supply Current	5.5	−	8.0	80	μA	V_{IN} = V_{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.
†Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}.

AC CHARACTERISTICS (For Figures and Waveforms − See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

Symbol	Parameter	V_{CC}* (V)	74AC T_A = +25°C C_L = 50 pF			74AC T_A = −40°C to +85°C C_L = 50 pF		Unit	Fig. No.
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Clock to Bus	3.3 5.0	4.0 2.5	10.5 7.5	16.5 12	3.0 2.0	18.5 13	ns	3−6
t_{PHL}	Propagation Delay Clock to Bus	3.3 5.0	3.0 2.0	9.5 6.5	14.5 10.5	2.5 1.5	16 11.5	ns	3−6
t_{PLH}	Propagation Delay Bus to Bus	3.3 5.0	2.5 1.5	7.5 5.0	12 8.0	2.0 1.0	13.5 9.0	ns	3−5
t_{PHL}	Propagation Delay Bus to Bus	3.3 5.0	1.5 1.5	7.5 5.0	12.5 9.0	1.5 1.0	13.5 9.5	ns	3−5
t_{PLH}	Propagation Delay SBA or SAB to A_n or B_n (w/A_n or B_n HIGH or LOW)	3.3 5.0	2.0 1.5	8.5 6.0	13.5 10	1.5 1.5	15.5 11	ns	3−6
t_{PHL}	Propagation Delay SBA or SAB to A_n or B_n (w/A_n or B_n HIGH or LOW)	3.3 5.0	1.5 1.5	8.5 6.0	13.5 10	1.5 1.5	15 11	ns	3−6
t_{PZH}	Enable Time $\overline{G}$ to A_n or B_n	3.3 5.0	2.5 1.5	7.0 5.0	11.5 8.5	2.0 1.5	12.5 9.0	ns	3−7
t_{PZL}	Enable Time $\overline{G}$ to A_n or B_n	3.3 5.0	2.5 1.5	7.5 5.5	12.5 9.0	2.0 1.5	14 10	ns	3−8
t_{PHZ}	Disable Time $\overline{G}$ to A_n or B_n	3.3 5.0	3.0 2.0	8.0 6.5	12.5 10	2.5 2.0	13.5 11	ns	3−7
t_{PLZ}	Disable Time $\overline{G}$ to A_n or B_n	3.3 5.0	2.0 1.5	7.5 6.0	12 9.5	2.0 1.5	13.5 10.5	ns	3−8
t_{PZH}	Enable Time DIR to A_n or B_n	3.3 5.0	2.0 1.5	6.5 5.0	11 7.5	1.5 1.0	12 8.5	ns	3−7
t_{PZL}	Enable Time DIR to A_n or B_n	3.3 5.0	2.5 1.5	7.0 5.0	11.5 8.0	2.0 1.0	13 9.0	ns	3−8
t_{PHZ}	Disable Time DIR to A_n or B_n	3.3 5.0	2.5 1.5	7.5 5.5	11.5 9.5	1.5 1.5	12.5 10	ns	3−7
t_{PLZ}	Disable Time DIR to A_n or B_n	3.3 5.0	1.5 1.5	7.5 5.5	12 9.5	1.5 1.5	13.5 10.5	ns	3−8

*Voltage Range 3.3 V is 3.3 V ±0.3 V.
Voltage Range 5.0 V is 5.0 V ±0.5 V.

AC OPERATING REQUIREMENTS

Symbol	Parameter	V_{CC}* (V)	74AC T_A = +25°C C_L = 50 pF		74AC T_A = −40°C to +85°C C_L = 50 pF	Unit	Fig. No.
			Typ	Guaranteed Minimum			
t_s	Setup Time, HIGH or LOW Bus to Clock	3.3 5.0	2.0 1.5	5.0 4.0	5.5 4.5	ns	3−9
t_h	Hold Time, HIGH or LOW Bus to Clock	3.3 5.0	−1.5 −0.5	0 0.5	0 1.0	ns	3−9
t_w	Clock Pulse Width HIGH or LOW	3.3 5.0	2.0 2.0	3.5 3.5	4.5 3.5	ns	3−6

*Voltage Range 3.3 V is 3.3 V ±0.3 V.
Voltage Range 5.0 V is 5.0 V ±0.5 V.

DC CHARACTERISTICS

Symbol	Parameter	V_{CC} (V)	74ACT T_A = +25°C		74ACT T_A = −40°C to +85°C	Unit	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1 V or V_{CC} − 0.1 V
V_{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1 V or V_{CC} − 0.1 V
V_{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5	− −	3.86 4.86	3.76 4.76	V	*V_{IN} = V_{IL} or V_{IH} I_{OH} −24 mA −24 mA
V_{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5	− −	0.36 0.36	0.44 0.44	V	*V_{IN} = V_{IL} or V_{IH} I_{OL} 24 mA 24 mA
I_{IN}	Maximum Input Leakage Current	5.5	−	±0.1	±1.0	μA	V_I = V_{CC}, GND
ΔI_{CCT}	Additional Max. I_{CC}/Input	5.5	0.6	−	1.5	mA	V_I = V_{CC} − 2.1 V
I_{OZT}	Maximum 3-State Current	5.5	−	±0.6	±6.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	†Minimum Dynamic Output Current	5.5	−	−	75	mA	V_{OLD} = 1.65 V Max
I_{OHD}		5.5	−	−	−75	mA	V_{OHD} = 3.85 V Min
I_{CC}	Maximum Quiescent Supply Current	5.5	−	8.0	80	μA	V_{IN} = V_{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.
†Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms − See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

Symbol	Parameter	V_{CC}* (V)	74ACT T_A = +25°C, C_L = 50 pF			74ACT T_A = −40°C to +85°C, C_L = 50 pF		Unit	Fig. No.
			Min	Typ	Max	Min	Max		
t_{PLH}	Propagation Delay Clock to Bus	5.0	3.5	12.0	14.5	3.0	16.0	ns	3−6
t_{PHL}	Propagation Delay Clock to Bus	5.0	4.0	12.0	14.5	3.5	16.0	ns	3−6
t_{PLH}	Propagation Delay Bus to Bus	5.0	3.0	8.5	11.0	2.5	12.0	ns	3−5
t_{PHL}	Propagation Delay Bus to Bus	5.0	2.5	8.5	11.0	2.0	12.0	ns	3−5
t_{PLH}	Propagation Delay SBA or SAB to A_n or B_n (w/A_n or B_n HIGH or LOW)	5.0	3.0	9.5	12.0	2.5	13.0	ns	3−6
t_{PHL}	Propagation Delay SBA or SAB to A_n or B_n (w/A_n or B_n HIGH or LOW)	5.0	3.0	9.5	12.0	2.5	13.0	ns	3−6
t_{PZH}	Enable Time $\overline{G}$ to A_n or B_n	5.0	2.0	9.0	11.0	1.5	12.0	ns	3−7
t_{PZL}	Enable Time $\overline{G}$ to A_n or B_n	5.0	3.5	9.0	11.0	3.0	12.0	ns	3−8
t_{PHZ}	Disable Time $\overline{G}$ to A_n or B_n	5.0	5.0	10.5	13.0	4.5	14.5	ns	3−7
t_{PLZ}	Disable Time $\overline{G}$ to A_n or B_n	5.0	3.5	10.0	12.5	3.0	14.0	ns	3−8
t_{PZH}	Enable Time DIR to A_n or B_n	5.0	2.0	6.5	12.5	1.5	13.5	ns	3−7
t_{PZL}	Enable Time DIR to A_n or B_n	5.0	3.5	6.5	12.5	3.0	13.5	ns	3−8
t_{PHZ}	Disable Time DIR to A_n or B_n	5.0	5.0	8.5	12.5	4.5	13.5	ns	3−7
t_{PLZ}	Disable Time DIR to A_n or B_n	5.0	3.5	8.5	12.5	3.0	13.5	ns	3−8

*Voltage Range 5.0 V is 5.0 V ±0.5 V.

AC OPERATING REQUIREMENTS

Symbol	Parameter	V_{CC}* (V)	74ACT T_A = +25°C C_L = 50 pF		74ACT T_A = −40°C to +85°C C_L = 50 pF	Unit	Fig. No.
			Typ	Guaranteed Minimum			
t_s	Setup Time, HIGH or LOW Bus to Clock	5.0	−	7.0	8.0	ns	3−9
t_h	Hold Time, HIGH or LOW Bus to Clock	5.0	−	2.5	2.5	ns	3−9
t_w	Clock Pulse Width HIGH or LOW	5.0	−	7.0	8.0	ns	3−6

*Voltage Range 5.0 V is 5.0 V ±0.5 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = 5.0 V
$C_{I/O}$	Input/Output Capacitance	15	pF	V_{CC} = 5.0 V
C_{PD}	Power Dissipation Capacitance	60	pF	V_{CC} = 5.0 V

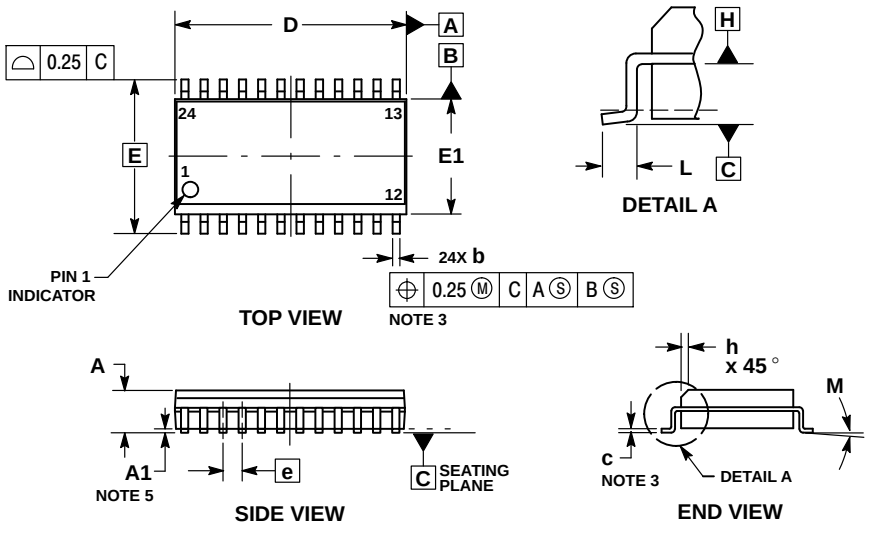
ORDERING INFORMATION

Device	Package	Shipping†
MC74AC646DWR2G	SOIC−24 (Pb−Free)	1000 / Tape & Reel
MC74ACT646DWG		30 Units / Rail
MC74ACT646DWR2G		1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

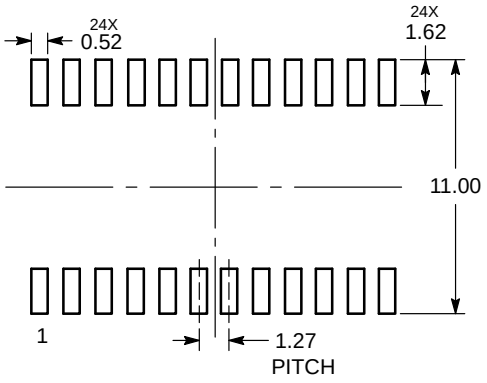
SOIC−24 WB
DW SUFFIX
CASE 751E−04
ISSUE F



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD AND ARE MEASURED BETWEEN 0.10 AND 0.25 FROM THE LEAD TIP.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

	MILLIMETERS	
DIM	MIN	MAX
A	2.35	2.65
A1	0.13	0.29
b	0.35	0.49
c	0.23	0.32
D	15.25	15.54
E	10.30 BSC	
E1	7.40	7.60
e	1.27 BSC	
h	0.25	0.75
L	0.41	0.90
M	0 °	8 °

RECOMMENDED
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81−3−5817−1050

ON Semiconductor Website: **www.onsemi.com**

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bus Transceivers ***category:***

Click to view products by ON Semiconductor ***manufacturer:***

Other Similar products are found below :

74LS645N PI74LVCC3245AS 5962-8683401DA 5962-8968201LA 5962-8953501KA 5962-86834012A 5962-7802002MFA TC74VCX164245(EL,F MC74LCX245MNTWG TC7WPB8306L8X,LF(S 74LVX245MTC 74ALVC16245MTDX 74LCXR162245MTX 74LVXC3245MTCX 74VHC245M 74VHC245MX JM38510/65553BRA FXL2TD245L10X 74LVC1T45GM,115 74LVC245ADTR2G TC74AC245P(F) SNJ54LS245FK 74LVT245BBT20-13 74AHC245D.112 74AHCT245D.112 SN74LVCH16952ADGGR CY74FCT16245TPVCT 74AHCT245PW.118 74LV245DB.118 74LV245D.112 74LV245PW.112 74LVC2245APW.112 74LVCH245AD.112 SN75138NSR AP54RHC506ELT-R AP54RHC506BLT-R 74LVCR162245ZQLR SN74LVCR16245AZQLR MC100EP16MNR4G MC100LVEP16MNR4G 714100R 74HCT643N MC100EP16DTR2G 5962-9221403MRA 74ALVC164245PAG 74FCT16245ATPAG 74FCT16245ATPVG 74FCT16245ETPAG 74FCT245CTSOG 74LVC162245APAG8